

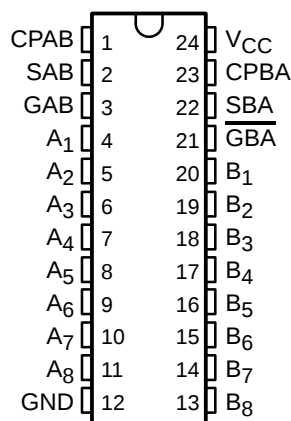
# CY74FCT652T

## 8-BIT REGISTERED TRANSCEIVER WITH 3-STATE OUTPUTS

SCCS032B – SEPTEMBER 1994 – REVISED OCTOBER 2001

- Function, Pinout, and Drive Compatible With FCT and F Logic
- Reduced  $V_{OH}$  (Typically = 3.3 V) Version of Equivalent FCT Functions
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- $I_{off}$  Supports Partial-Power-Down Mode Operation
- Matched Rise and Fall Times
- Fully Compatible With TTL Input and Output Logic Levels
- 64-mA Output Sink Current  
32-mA Output Source Current
- Independent Register for A and B Buses
- Multiplexed Real-Time and Stored Data Transfer
- 3-State Outputs

Q OR SO PACKAGE  
(TOP VIEW)



### description

The CY74FCT652T consists of bus transceiver circuits, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal storage registers. GAB and  $\overline{GBA}$  inputs control the transceiver functions. Select-control (SAB and SBA) inputs select either real-time or stored-data transfer. The circuitry used for select control eliminates the typical decoding glitch that occurs in a multiplexer during the transition between stored and real-time data. A low input level selects real-time data, and a high input level selects stored data.

Data on the A or B data bus, or both, can be stored in the internal D-type flip-flops by low-to-high transitions of the appropriate clock (CPAB or CPBA) inputs, regardless of the select or enable levels of the control pins. When SAB and SBA are in the real-time transfer mode, it also is possible to store data without using the internal D-type flip-flops by simultaneously enabling GAB and  $\overline{GBA}$ . In this configuration, each output reinforces its input. Thus, when all other data sources to the two sets of bus lines are at high impedance, each set of bus lines remains at its last state.

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

 **TEXAS  
INSTRUMENTS**

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# CY74FCT652T

## 8-BIT REGISTERED TRANSCEIVER

### WITH 3-STATE OUTPUTS

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#### ORDERING INFORMATION

| T <sub>A</sub> | PACKAGE <sup>†</sup> |               | SPEED (ns) | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|----------------|----------------------|---------------|------------|-----------------------|------------------|
| –40°C to 85°C  | QSOP – Q             | Tape and reel | 5.4        | CY74FCT652CTQCT       | FCT652C          |
|                | SOIC – SO            | Tube          | 5.4        | CY74FCT652CTSOC       | FCT652C          |
|                |                      | Tape and reel | 5.4        | CY74FCT652CTSOCT      |                  |
|                | QSOP – Q             | Tape and reel | 6.3        | CY74FCT652ATQCT       | FCT652A          |
|                | SOIC – SO            | Tube          | 6.3        | CY74FCT652ATSOC       | FCT652A          |
|                |                      | Tape and reel | 6.3        | CY74FCT652ATSOCT      |                  |
|                | QSOP – Q             | Tape and reel | 9          | CY74FCT652TQCT        | FCT652           |

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).

#### FUNCTION TABLE

| INPUTS |                         |        |        |                |                | DATA I/O                       |                                | OPERATION OR FUNCTION                             |
|--------|-------------------------|--------|--------|----------------|----------------|--------------------------------|--------------------------------|---------------------------------------------------|
| GAB    | $\overline{\text{GBA}}$ | CPAB   | CPBA   | SAB            | SBA            | A <sub>1</sub> –A <sub>8</sub> | B <sub>1</sub> –B <sub>8</sub> |                                                   |
| L      | H                       | H or L | H or L | X              | X              | Input                          | Input                          | Isolation                                         |
| L      | H                       | ↑      | ↑      | X              | X              | Input                          | Input                          | Store A and B data                                |
| X      | H                       | ↑      | H or L | X              | X              | Input                          | Unspecified <sup>§</sup>       | Store A, hold B                                   |
| H      | H                       | ↑      | ↑      | X <sup>‡</sup> | X              | Input                          | Output                         | Store A in both registers                         |
| L      | X                       | H or L | ↑      | X              | X              | Unspecified <sup>§</sup>       | Input                          | Hold A, store B                                   |
| L      | L                       | ↑      | ↑      | X              | X <sup>‡</sup> | Output                         | Input                          | Store B in both registers                         |
| L      | L                       | X      | X      | X              | L              | Output                         | Input                          | Real-time B data to A bus                         |
| L      | L                       | X      | H or L | X              | H              | Output                         | Input                          | Stored B data to A bus                            |
| H      | H                       | X      | X      | L              | X              | Input                          | Output                         | Real-time A data to B bus                         |
| H      | H                       | H or L | X      | H              | X              | Input                          | Output                         | Stored A data to B bus                            |
| H      | L                       | H or L | H or L | H              | H              | Output                         | Output                         | Stored A data to B bus and Stored B data to A bus |

H = High logic level, L = Low logic level, X = Don't care, ↑ = Low-to-high transition

<sup>‡</sup> Select control = L: clocks can occur simultaneously. Select control = H: clocks must be staggered in order to load both registers.

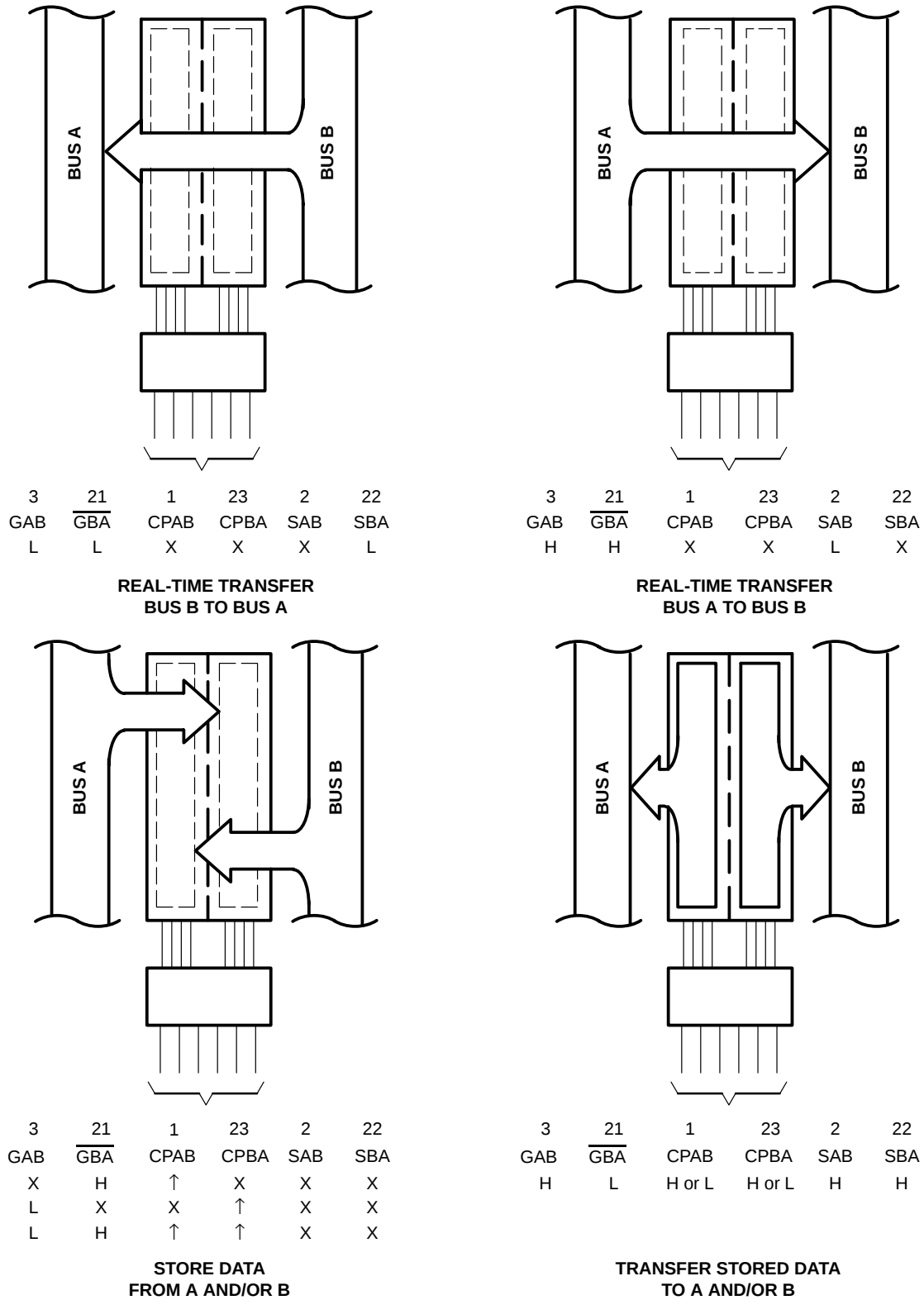
<sup>§</sup> The data output functions can be enabled or disabled by various signals at the GAB and  $\overline{\text{GBA}}$  inputs. Data input functions always are enabled, i.e., data at the bus pins are stored on every low-to-high transition of the clock inputs.



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**Figure 1. Bus-Management Functions**

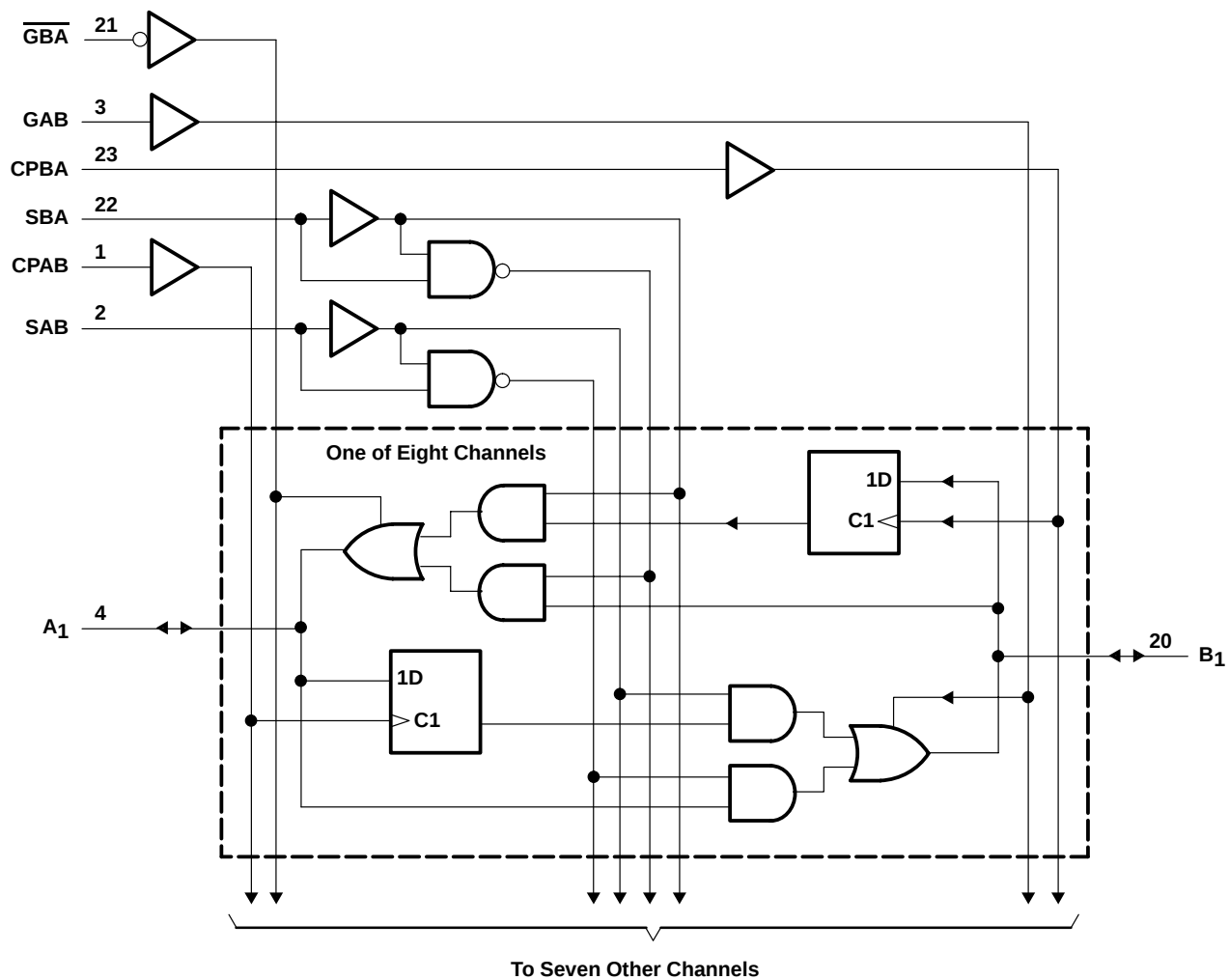
# CY74FCT652T

## 8-BIT REGISTERED TRANSCEIVER

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#### logic diagram (positive logic)



**CY74FCT652T**  
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**absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>**

|                                                                        |                |
|------------------------------------------------------------------------|----------------|
| Supply voltage range to ground potential .....                         | –0.5 V to 7 V  |
| DC input voltage range .....                                           | –0.5 V to 7 V  |
| DC output voltage range .....                                          | –0.5 V to 7 V  |
| DC output current (maximum sink current/pin) .....                     | 120 mA         |
| Package thermal impedance, $\theta_{JA}$ (see Note 1): Q package ..... | 61°C/W         |
| SO package .....                                                       | 46°C/W         |
| Ambient temperature range with power applied, $T_A$ .....              | –65°C to 135°C |
| Storage temperature range, $T_{Stg}$ .....                             | –65°C to 150°C |

<sup>†</sup> Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The package thermal impedance is calculated in accordance with JESD 51-7.

**recommended operating conditions (see Note 2)**

|                                      | MIN  | NOM | MAX  | UNIT |
|--------------------------------------|------|-----|------|------|
| $V_{CC}$ Supply voltage              | 4.75 | 5   | 5.25 | V    |
| $V_{IH}$ High-level input voltage    | 2    |     |      | V    |
| $V_{IL}$ Low-level input voltage     |      |     | 0.8  | V    |
| $I_{OH}$ High-level output current   |      |     | –32  | mA   |
| $I_{OL}$ Low-level output current    |      |     | 64   | mA   |
| $T_A$ Operating free-air temperature | –40  |     | 85   | °C   |

NOTE 2: All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation.



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## 8-BIT REGISTERED TRANSCEIVER

### WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER                   | TEST CONDITIONS                                                                                                                                                       |                                                                    | MIN                                                                  | TYP† | MAX  | UNIT   |
|-----------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------|----------------------------------------------------------------------|------|------|--------|
| V <sub>IK</sub>             | V <sub>CC</sub> = 4.75 V,                                                                                                                                             | I <sub>IN</sub> = −18 mA                                           |                                                                      | −0.7 | −1.2 | V      |
| V <sub>OH</sub>             | V <sub>CC</sub> = 4.75 V                                                                                                                                              | I <sub>OH</sub> = −32 mA                                           | 2                                                                    |      |      | V      |
|                             |                                                                                                                                                                       | I <sub>OH</sub> = −15 mA                                           | 2.4                                                                  | 3.3  |      |        |
| V <sub>OL</sub>             | V <sub>CC</sub> = 4.75 V,                                                                                                                                             | I <sub>OL</sub> = 64 mA                                            |                                                                      | 0.3  | 0.55 | V      |
| V <sub>hys</sub>            | All inputs                                                                                                                                                            |                                                                    |                                                                      | 0.2  |      | V      |
| I <sub>I</sub>              | V <sub>CC</sub> = 5.25 V,                                                                                                                                             | V <sub>IN</sub> = V <sub>CC</sub>                                  |                                                                      |      | 5    | μA     |
| I <sub>IH</sub>             | V <sub>CC</sub> = 5.25 V,                                                                                                                                             | V <sub>IN</sub> = 2.7 V                                            |                                                                      |      | ±1   | μA     |
| I <sub>IL</sub>             | V <sub>CC</sub> = 5.25 V,                                                                                                                                             | V <sub>IN</sub> = 0.5 V                                            |                                                                      |      | ±1   | μA     |
| I <sub>OZH</sub>            | V <sub>CC</sub> = 5.25 V,                                                                                                                                             | V <sub>OUT</sub> = 2.7 V                                           |                                                                      |      | 10   | μA     |
| I <sub>OZL</sub>            | V <sub>CC</sub> = 5.25 V,                                                                                                                                             | V <sub>OUT</sub> = 0.5 V                                           |                                                                      |      | −10  | μA     |
| I <sub>OS</sub> ‡           | V <sub>CC</sub> = 5.25 V,                                                                                                                                             | V <sub>OUT</sub> = 0 V                                             | −60                                                                  | −120 | −225 | mA     |
| I <sub>off</sub>            | V <sub>CC</sub> = 0 V,                                                                                                                                                | V <sub>OUT</sub> = 4.5 V                                           |                                                                      |      | ±1   | μA     |
| I <sub>CC</sub>             | V <sub>CC</sub> = 5.25 V,                                                                                                                                             | V <sub>IN</sub> ≤ 0.2 V, V <sub>IN</sub> ≥ V <sub>CC</sub> − 0.2 V |                                                                      | 0.1  | 0.2  | mA     |
| ΔI <sub>CC</sub>            | V <sub>CC</sub> = 5.25 V, V <sub>IN</sub> = 3.4 V <sup>§</sup> , f <sub>1</sub> = 0, Outputs open                                                                     |                                                                    |                                                                      | 0.5  | 2    | mA     |
| I <sub>CCD</sub> ¶          | V <sub>CC</sub> = 5.25 V, One input switching at 50% duty cycle, Outputs open, GAB or GBA = GND, V <sub>IN</sub> ≤ 0.2 V or V <sub>IN</sub> ≥ V <sub>CC</sub> − 0.2 V |                                                                    |                                                                      | 0.06 | 0.12 | mA/MHz |
| I <sub>C</sub> <sup>#</sup> | V <sub>CC</sub> = 5.25 V, f <sub>0</sub> = 10 MHz, Outputs open, GAB = GBA = GND, SAB = CPAB = GND, SBA = V <sub>CC</sub>                                             | One bit switching at f <sub>1</sub> = 5 MHz at 50% duty cycle      | V <sub>IN</sub> ≤ 0.2 V or V <sub>IN</sub> ≥ V <sub>CC</sub> − 0.2 V | 0.7  | 1.4  | mA     |
|                             |                                                                                                                                                                       |                                                                    | V <sub>IN</sub> = 3.4 V or GND                                       | 1.2  | 3.4  |        |
|                             |                                                                                                                                                                       | Eight bits switching at f <sub>1</sub> = 5 MHz at 50% duty cycle   | V <sub>IN</sub> ≤ 0.2 V or V <sub>IN</sub> ≥ V <sub>CC</sub> − 0.2 V | 2.8  | 5.6  |        |
|                             |                                                                                                                                                                       |                                                                    | V <sub>IN</sub> = 3.4 V or GND                                       | 5.1  | 14.6 |        |
| C <sub>i</sub>              |                                                                                                                                                                       |                                                                    |                                                                      | 5    | 10   | pF     |
| C <sub>o</sub>              |                                                                                                                                                                       |                                                                    |                                                                      | 9    | 12   | pF     |

<sup>†</sup> Typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^\circ\text{C}$ .

<sup>‡</sup> Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests,  $I_{OS}$  tests should be performed last.

<sup>\S</sup> Per TTL-driven input ( $V_{IN} = 3.4 \text{ V}$ ); all other inputs at  $V_{CC}$  or GND

<sup>\P</sup> This parameter is derived for use in total power-supply calculations.

<sup>\#</sup>  $I_C = I_{CC} + \Delta I_{CC} \times D_H \times N_T + I_{CCD} (f_0/2 + f_1 \times N_1)$

Where:

$I_C$  = Total supply current

$I_{CC}$  = Power-supply current with CMOS input levels

$\Delta I_{CC}$  = Power-supply current for a TTL high input ( $V_{IN} = 3.4 \text{ V}$ )

$D_H$  = Duty cycle for TTL inputs high

$N_T$  = Number of TTL inputs at  $D_H$

$I_{CCD}$  = Dynamic current caused by an input transition pair (HLH or LHL)

$f_0$  = Clock frequency for registered devices, otherwise zero

$f_1$  = Input signal frequency

$N_1$  = Number of inputs changing at  $f_1$

All currents are in milliamperes and all frequencies are in megahertz.

|| Values for these conditions are examples of the  $I_{CC}$  formula.



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**timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)**

|          |                                                       | CY74FCT652T |     | CY74FCT652AT |     | CY74FCT652CT |     | UNIT |
|----------|-------------------------------------------------------|-------------|-----|--------------|-----|--------------|-----|------|
|          |                                                       | MIN         | MAX | MIN          | MAX | MIN          | MAX |      |
| $t_W$    | Pulse duration, clock high or low                     | 6           |     | 5            |     | 5            |     | ns   |
| $t_{SU}$ | Setup time, before CPAB $\uparrow$ or CPBA $\uparrow$ | 4           |     | 2            |     | 2            |     | ns   |
| $t_H$    | Hold time, after CPAB $\uparrow$ or CPBA $\uparrow$   | 2           |     | 1.5          |     | 1.5          |     | ns   |

**switching characteristics over operating free-air temperature range (see Figure 2)**

| PARAMETER | FROM<br>(INPUT)         | TO<br>(OUTPUT) | CY74FCT652T |     | CY74FCT652AT |     | CY74FCT652CT |     | UNIT |
|-----------|-------------------------|----------------|-------------|-----|--------------|-----|--------------|-----|------|
|           |                         |                | MIN         | MAX | MIN          | MAX | MIN          | MAX |      |
| $t_{PLH}$ | A or B                  | B or A         | 1.5         | 9   | 1.5          | 6.3 | 1.5          | 5.4 | ns   |
| $t_{PHL}$ |                         |                | 1.5         | 9   | 1.5          | 6.3 | 1.5          | 5.4 |      |
| $t_{PZH}$ | GAB or $\overline{GBA}$ | A or B         | 1.5         | 14  | 1.5          | 9.8 | 1.5          | 7.8 | ns   |
| $t_{PZL}$ |                         |                | 1.5         | 14  | 1.5          | 9.8 | 1.5          | 7.8 |      |
| $t_{PHZ}$ | GAB or $\overline{GBA}$ | A or B         | 1.5         | 9   | 1.5          | 6.3 | 1.5          | 6.3 | ns   |
| $t_{PLZ}$ |                         |                | 1.5         | 9   | 1.5          | 6.3 | 1.5          | 6.3 |      |
| $t_{PLH}$ | CPAB or CPBA            | A or B         | 1.5         | 9   | 1.5          | 6.3 | 1.5          | 5.7 | ns   |
| $t_{PHL}$ |                         |                | 1.5         | 9   | 1.5          | 6.3 | 1.5          | 5.7 |      |
| $t_{PLH}$ | SBA or SAB              | A or B         | 1.5         | 11  | 1.5          | 7.7 | 1.5          | 6.2 | ns   |
| $t_{PHL}$ |                         |                | 1.5         | 11  | 1.5          | 7.7 | 1.5          | 6.2 |      |

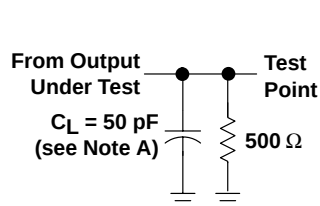
# CY74FCT652T

## 8-BIT REGISTERED TRANSCEIVER

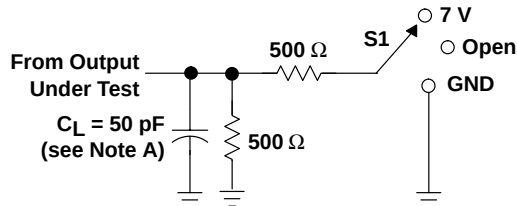
### WITH 3-STATE OUTPUTS

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#### PARAMETER MEASUREMENT INFORMATION

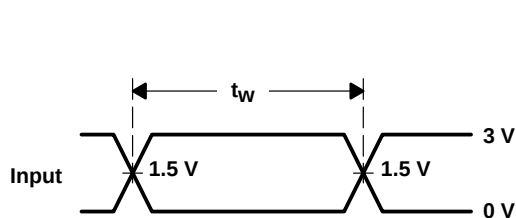


LOAD CIRCUIT FOR  
TOTEM-POLE OUTPUTS

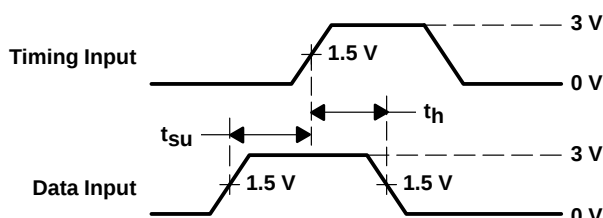


LOAD CIRCUIT FOR  
3-STATE OUTPUTS

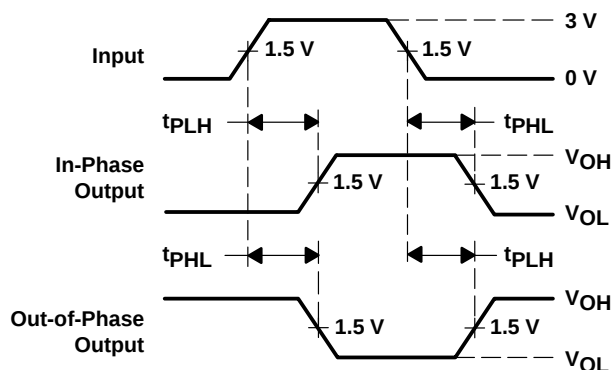
| TEST              | S1   |
|-------------------|------|
| $t_{PLH}/t_{PHL}$ | Open |
| $t_{PLZ}/t_{PZL}$ | 7 V  |
| $t_{PHZ}/t_{PZH}$ | Open |



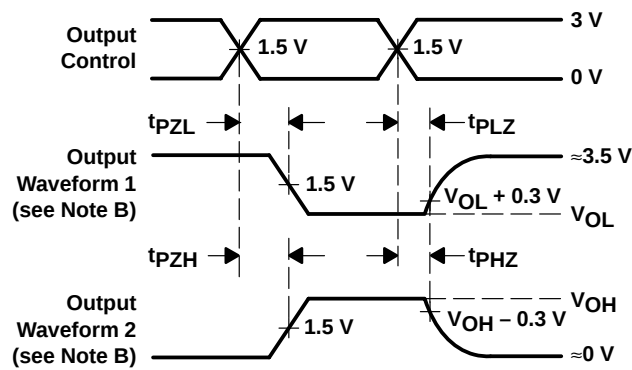
VOLTAGE WAVEFORMS  
PULSE DURATION



VOLTAGE WAVEFORMS  
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS  
PROPAGATION DELAY TIMES  
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS  
ENABLE AND DISABLE TIMES  
LOW- AND HIGH-LEVEL ENABLING

NOTES: A.  $C_L$  includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

C. The outputs are measured one at a time with one input transition per measurement.

Figure 2. Load Circuit and Voltage Waveforms

## PACKAGING INFORMATION

| Orderable part number            | Status<br>(1) | Material type<br>(2) | Package   Pins  | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|----------------------------------|---------------|----------------------|-----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">CY74FCT652ATQCT</a>  | Active        | Production           | SSOP (DBQ)   24 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | FCT652A             |
| CY74FCT652ATQCT.B                | Active        | Production           | SSOP (DBQ)   24 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | FCT652A             |
| <a href="#">CY74FCT652ATSOC</a>  | Active        | Production           | SOIC (DW)   24  | 25   TUBE             | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | FCT652A             |
| CY74FCT652ATSOC.B                | Active        | Production           | SOIC (DW)   24  | 25   TUBE             | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | FCT652A             |
| <a href="#">CY74FCT652ATSOCT</a> | Active        | Production           | SOIC (DW)   24  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | FCT652A             |
| CY74FCT652ATSOCT.B               | Active        | Production           | SOIC (DW)   24  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | FCT652A             |
| <a href="#">CY74FCT652CTQCT</a>  | Active        | Production           | SSOP (DBQ)   24 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | FCT652C             |
| CY74FCT652CTQCT.B                | Active        | Production           | SSOP (DBQ)   24 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | FCT652C             |
| CY74FCT652CTQCTG4                | Active        | Production           | SSOP (DBQ)   24 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | FCT652C             |
| CY74FCT652CTQCTG4.B              | Active        | Production           | SSOP (DBQ)   24 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | FCT652C             |
| <a href="#">CY74FCT652CTSOCT</a> | Active        | Production           | SOIC (DW)   24  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | FCT652C             |
| CY74FCT652CTSOCT.B               | Active        | Production           | SOIC (DW)   24  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | FCT652C             |
| <a href="#">CY74FCT652TQCT</a>   | Active        | Production           | SSOP (DBQ)   24 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | FCT652              |
| CY74FCT652TQCT.B                 | Active        | Production           | SSOP (DBQ)   24 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | FCT652              |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device            | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-------------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| CY74FCT652ATQCT   | SSOP         | DBQ             | 24   | 2500 | 330.0              | 16.4               | 6.5     | 9.0     | 2.1     | 8.0     | 16.0   | Q1            |
| CY74FCT652ATSOCT  | SOIC         | DW              | 24   | 2000 | 330.0              | 24.4               | 10.75   | 15.7    | 2.7     | 12.0    | 24.0   | Q1            |
| CY74FCT652CTQCT   | SSOP         | DBQ             | 24   | 2500 | 330.0              | 16.4               | 6.5     | 9.0     | 2.1     | 8.0     | 16.0   | Q1            |
| CY74FCT652CTQCTG4 | SSOP         | DBQ             | 24   | 2500 | 330.0              | 16.4               | 6.5     | 9.0     | 2.1     | 8.0     | 16.0   | Q1            |
| CY74FCT652CTSOCT  | SOIC         | DW              | 24   | 2000 | 330.0              | 24.4               | 10.75   | 15.7    | 2.7     | 12.0    | 24.0   | Q1            |
| CY74FCT652TQCT    | SSOP         | DBQ             | 24   | 2500 | 330.0              | 16.4               | 6.5     | 9.0     | 2.1     | 8.0     | 16.0   | Q1            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device            | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|-------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| CY74FCT652ATQCT   | SSOP         | DBQ             | 24   | 2500 | 353.0       | 353.0      | 32.0        |
| CY74FCT652ATSOCT  | SOIC         | DW              | 24   | 2000 | 350.0       | 350.0      | 43.0        |
| CY74FCT652CTQCT   | SSOP         | DBQ             | 24   | 2500 | 353.0       | 353.0      | 32.0        |
| CY74FCT652CTQCTG4 | SSOP         | DBQ             | 24   | 2500 | 353.0       | 353.0      | 32.0        |
| CY74FCT652CTSOCT  | SOIC         | DW              | 24   | 2000 | 350.0       | 350.0      | 43.0        |
| CY74FCT652TQCT    | SSOP         | DBQ             | 24   | 2500 | 353.0       | 353.0      | 32.0        |

## TUBE

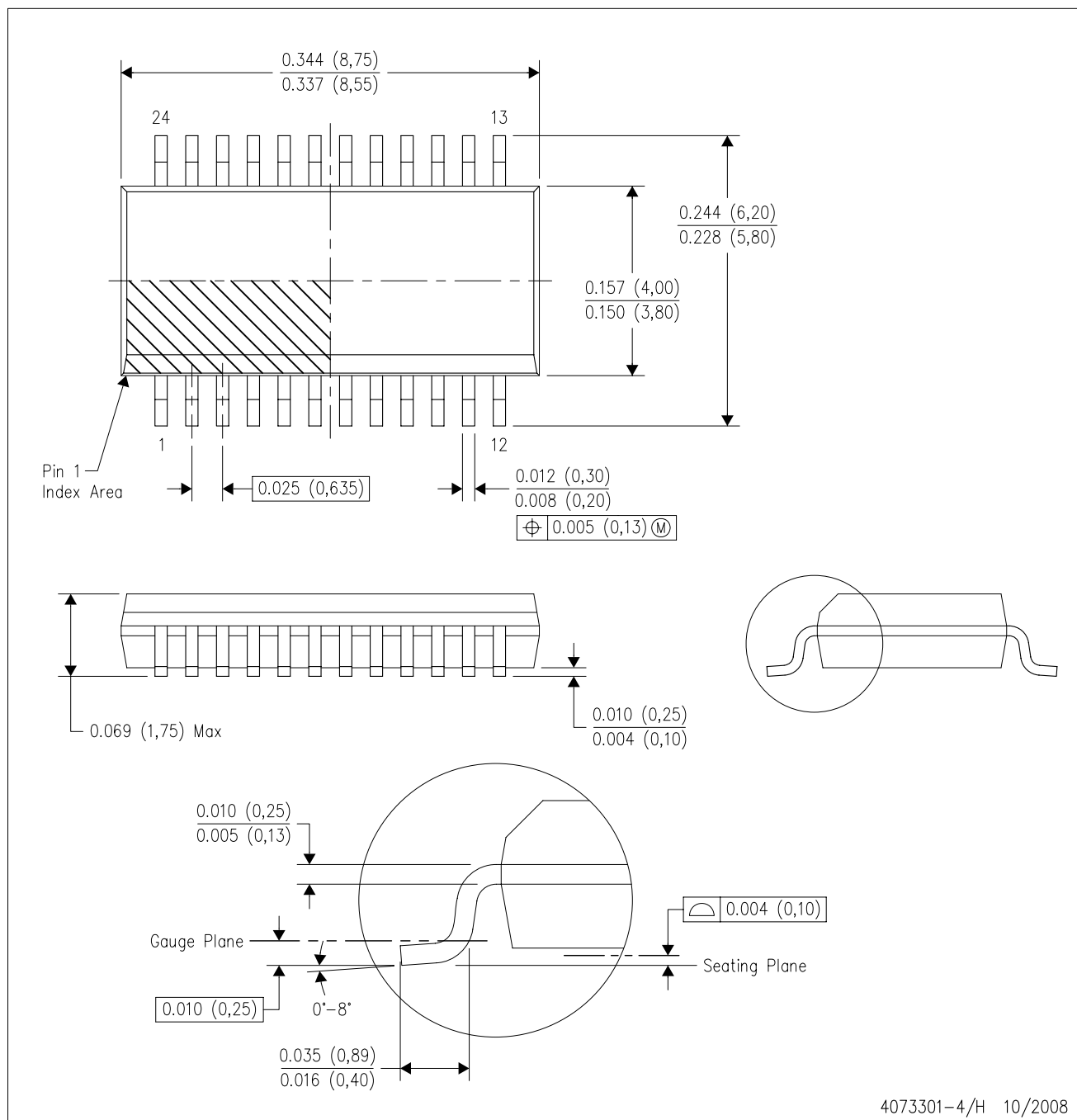


\*All dimensions are nominal

| Device            | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|-------------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| CY74FCT652ATSOC   | DW           | SOIC         | 24   | 25  | 506.98 | 12.7   | 4826   | 6.6    |
| CY74FCT652ATSOC.B | DW           | SOIC         | 24   | 25  | 506.98 | 12.7   | 4826   | 6.6    |

DBQ (R-PDSO-G24)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
  - D. Falls within JEDEC MO-137 variation AE.

DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
  - D. Falls within JEDEC MS-013 variation AD.

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